A thermodynamic probe of the topological phase transition in epitaxial graphene based Floquet topological insulator

Topological phase diagram which distinguishes the FTI(orange) and band insulator(blue) (I vs Δ). The boundary between them is the place where gap closes at K point. For left circularly polarized light the phase diagram remains same except I is replaced by I. The plot shows that a threshold value of photo illumination parameter (I) is always present for all values of Δ where the topological phase change occurs.

Work output WO (in units of nano Joule) and (b) Efficiency ηo of the QOE cycle are plotted versus $I_{_{+}}^{c}$ for three different values of $I_{_{+}}^{h} = 340$ meV (red), 350 meV (black), and 360 meV (blue). The temperatures of the cold and hot bath are Tc = 150K and Th = 300 K both for (Left) and (Right).



We have detected the photoinduced phase transition point in FTI using work and efficiency of QOE and QSE cycles. The work output and efficiency takes a two peak structure for QOE and is an extremum at the phase transition point. arXiv:2012.02172, A. Kumar and C. Benjamin